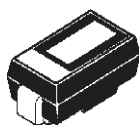
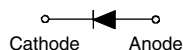


Schottky Rectifier, 1.0 A


SMB


FEATURES

- 125 °C T_J operation ($V_R < 5$ V)
- Optimized for OR-ing applications
- Ultralow forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Lead (Pb)-free ("PbF" suffix)
- Designed and qualified for industrial level


RoHS*
COMPLIANT

PRODUCT SUMMARY

$I_{F(AV)}$	1.0 A
V_R	15 V

DESCRIPTION

The 10BQ015PbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	1.0	A
V_{RRM}		15	V
I_{FSM}	$t_p = 5 \mu s$ sine	140	A
V_F	1.0 Apk, $T_J = 125$ °C	0.32	V
T_J	Range	- 55 to 125	°C

VOLTAGE RATINGS

PARAMETER	SYMBOL	10BQ015PbF	UNITS
Maximum DC reverse voltage	V_R	15	V
Maximum working peak reverse voltage	V_{RWM}	25	

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current See fig. 5	$I_{F(AV)}$	50 % duty cycle at $T_L = 84$ °C, rectangular waveform	1.0	A
Maximum peak one cycle non-repetitive surge current See fig. 7	I_{FSM}	5 μs sine or 3 μs rect. pulse	140	A
		10 ms sine or 6 ms rect. pulse	40	
Non-repetitive avalanche energy	E_{AS}	$T_J = 25$ °C, $I_{AS} = 1$ A, $L = 2$ mH	1.0	mJ
Repetitive avalanche current	I_{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical	1.0	A

* Pb containing terminations are not RoHS compliant, exemptions may apply

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	1 A	T _J = 25 °C	0.35	V	
		2 A		0.44		
		1 A	T _J = 125 °C	0.32		0.40
		2 A				
Maximum reverse leakage current See fig. 2	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	0.5	mA	
		T _J = 100 °C		12		
Threshold voltage	V _{F(TO)}	T _J = T _J maximum		-	V	
Forward slope resistance	r _t			-	mΩ	
Typical junction capacitance	C _T	V _R = 5 V _{DC} , (test signal range 100 kHz to 1 MHz) 25 °C		390	pF	
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		2.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/μs	

Note

(1) Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temperature range	T _J ⁽¹⁾		- 55 to 125	°C
Maximum storage temperature range	T _{Stg}		- 55 to 150	
Maximum thermal resistance, junction to lead	R _{thJL} ⁽²⁾	DC operation See fig. 4	36	°C/W
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	
Approximate weight			0.10	g
			0.003	oz.
Marking device		Case style SMB (similar to DO-214AA)	V1C	

Notes

(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

(2) Mounted 1" square PCB

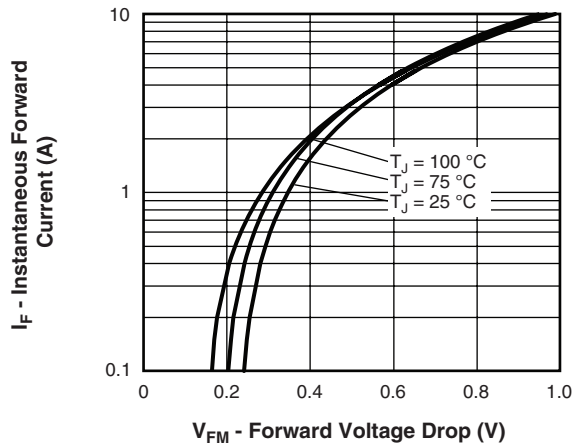


Fig. 1 - Maximum Forward Voltage Drop Characteristics

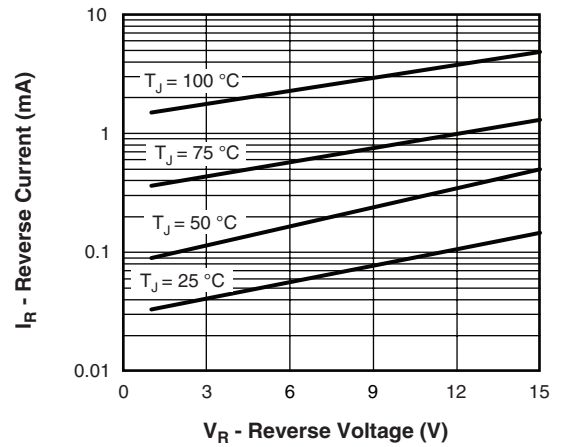


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

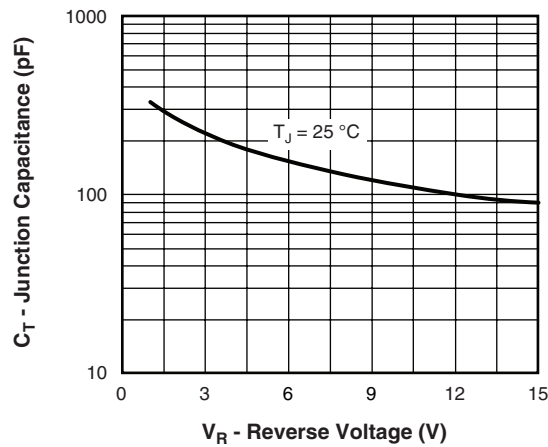


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

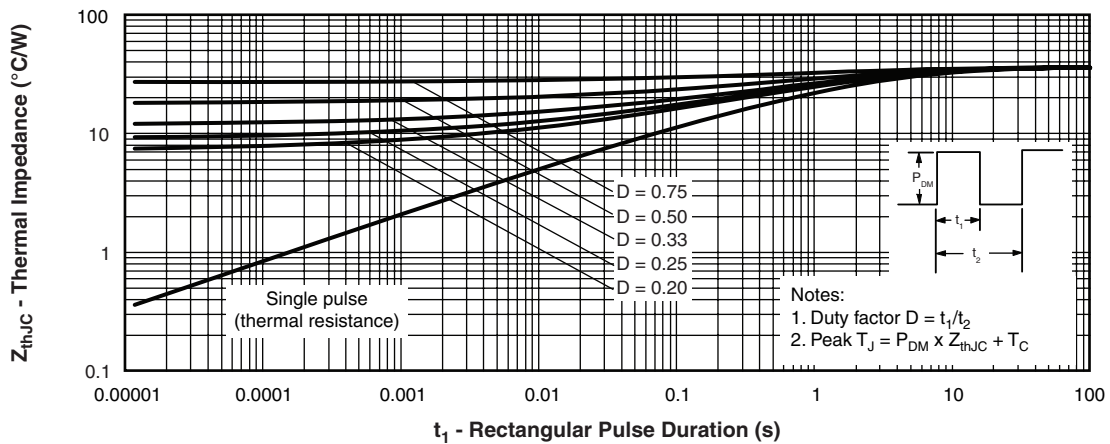


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

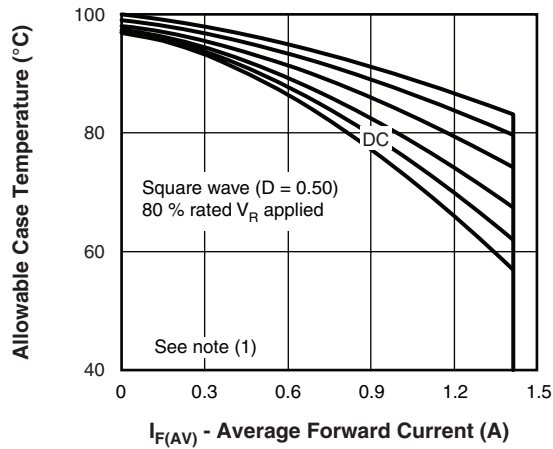


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

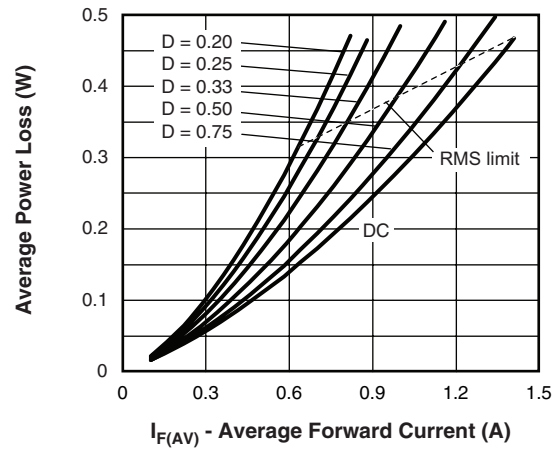


Fig. 6 - Forward Power Loss Characteristics

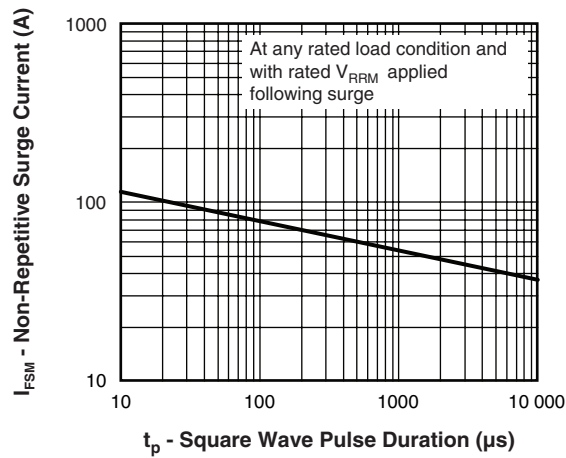


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;
 P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 $P_{d_{REV}}$ = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80\%$ rated V_R

**ORDERING INFORMATION TABLE**

Device code	10	B	Q	015	TR	PbF
	①	②	③	④	⑤	⑥

- | | | |
|----------|---|---|
| 1 | - | Current rating |
| 2 | - | B = Single lead diode |
| 3 | - | Q = Schottky "Q" series |
| 4 | - | Voltage rating (015 = 15 V) |
| 5 | - | <ul style="list-style-type: none">• None = Box (1000 pieces)• TR = Tape and reel (3000 pieces) |
| 6 | - | <ul style="list-style-type: none">• None = Standard production• PbF = Lead (Pb)-free |

LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95017
Part marking information	http://www.vishay.com/doc?95029
Packaging information	http://www.vishay.com/doc?95034
SPIICE model	http://www.vishay.com/doc?95355



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